Am9128

2048x8 Static RAM

Advanced Micro Devices

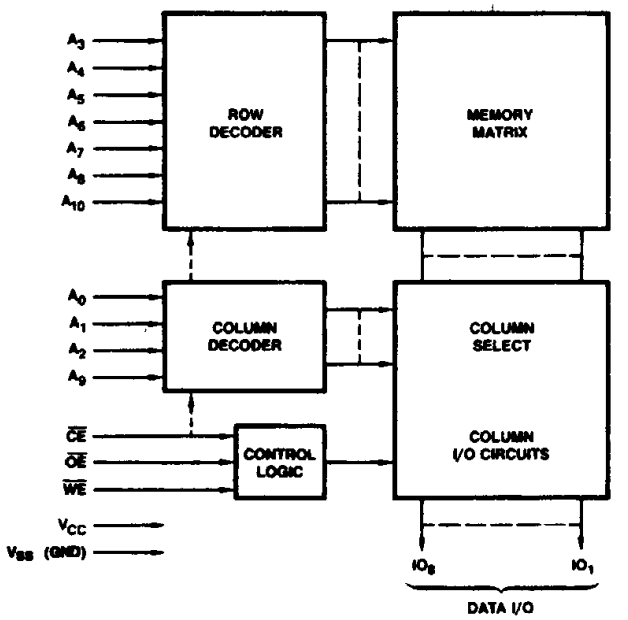
DISTINCTIVE CHARACTERISTICS

- Logic voltage levels compatible with TTL
- Three-state output buffers and common I/O
- I_{CC} Max., as low as 100 mA
- t_{AA}/t_{ACS} as low as 70 ns
- Power-Down mode (I_{SB} as low as 15 mA)

GENERAL DESCRIPTION

The Am9128 is a 16,384-bit Static Random = Access Read-write Memory organized as 2048 words of 8 bits. It uses fully static circuitry, requiring no clocks or refresh to operate. Directly TTL-compatible inputs and outputs and operation from a single +5 V supply simplify system designs. Common data I/O pins using three-state outputs are provided. The Am9128 is available in an industry-standard 24-pin DIP package with 0.6-inch pin row spacing. The Am9128 uses the JEDEC standard pinout for byte-wide memories (compatible to 16K EPROMs).

BLOCK DIAGRAM



BD000281

PRODUCT SELECTOR GUIDE

Part Number		Am9128-70	Am9128-90	Am9128-10	Am9128-12	Am9128-15	Am9128-20
Maximum Access Time (ns)		70	90	100	120	150	200
Maximum Operating Current (mA)	0 to 70°C	140	N/A	120	N/A	100	140
	−55° to 125°C	N/A	180	N/A	150	150	150
Maximum Standby Current (mA)	0° to 70°C	30	N/A	15	N/A	15	30
	−55° to 125°C	N/A	30	N/A	30	30	30

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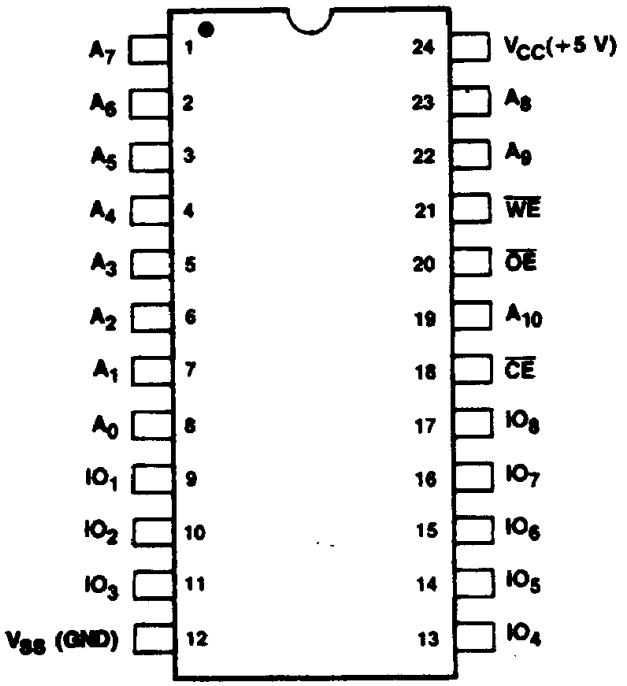
CONNECTION DIAGRAMS
Top View

DIPs



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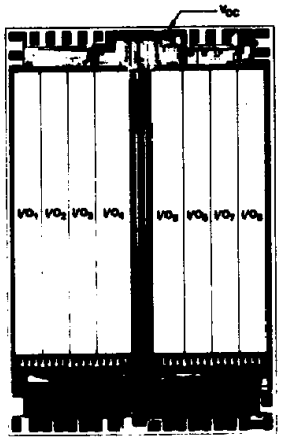
Note: Pin 1 is marked for orientation.

METALLIZATION AND PAD LAYOUT

Address Designators	
External	Internal
A_3	AX_0
A_4	AX_1
A_5	AX_2
A_6	AX_3
A_7	AX_4
A_8	AX_5
A_{10}	AX_6
A_0	AY_0
A_1	AY_1
A_2	AY_2
A_9	AY_3



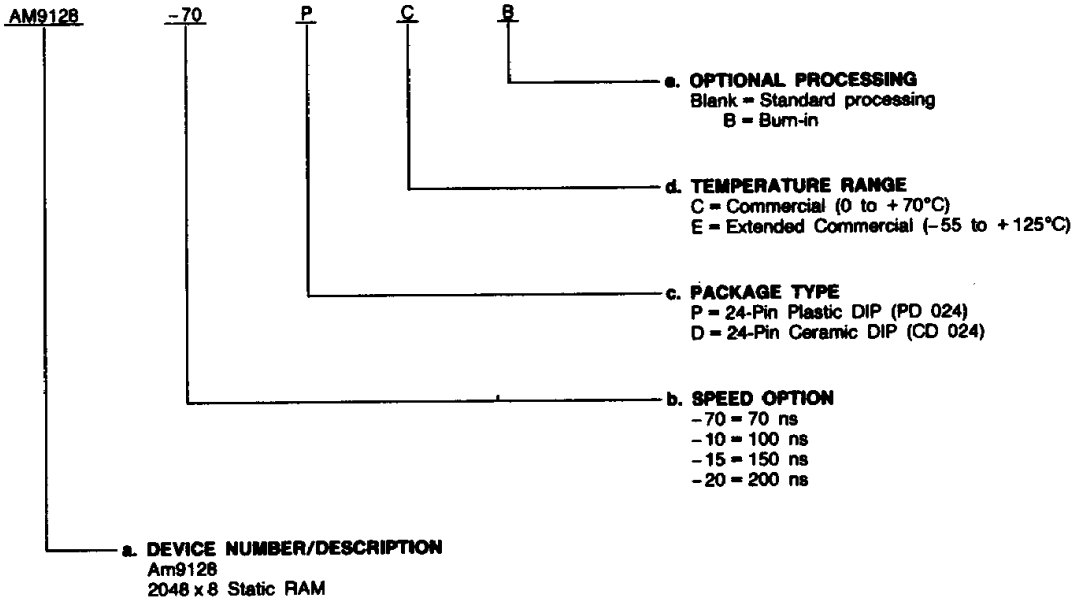
DIE SIZE: 0.162" x 0.240"

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:

a. Device Number
b. Speed Option (if applicable)
c. Package Type
d. Temperature Range
e. Optional Processing



Valid Combinations	
AM9128-70	PC, DC, DCB, DE, DEB
AM9128-10	
AM9128-15	
AM9128-20	

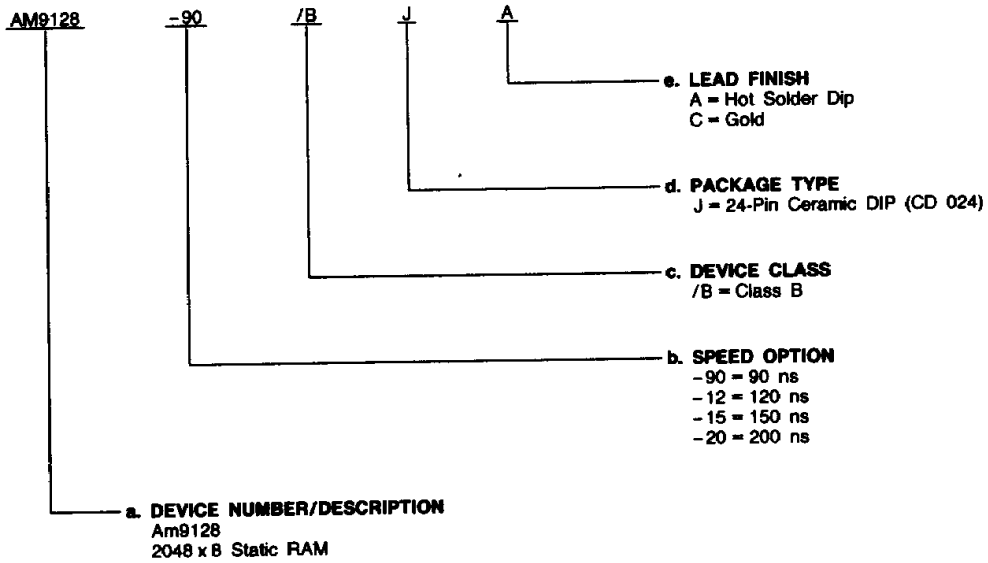
Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: **a. Device Number**
b. Speed Option (if applicable)
c. Device Class
d. Package Type
e. Lead Finish



Valid Combinations	
AM9128-90	/BJA, /BJC
AM9128-12	
AM9128-15	
AM9128-20	

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups
1, 2, 3, 7, 8, 9, 10, 11

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PIN DESCRIPTION

$A_0 - A_{10}$ Addresses (Input)
The 10-bit field presented at the address inputs selects one of the 2048 memory locations to be read from — or written into — via the data lines.

$I/O_1 - I/O_8$ Data In/Out Port (Input/Output)
If $\overline{WE}$ is LOW, the data represented on the I/O lines can be written into the selected memory location. If $\overline{WE}$ is HIGH, the I/O lines represent the data read from the selected memory location.

$\overline{CE}$ Chip Enable (Input, Active LOW)
Read and Write cycles can be executed only when $\overline{CE}$ is LOW.

$\overline{WE}$ Write Enable (Input, Active LOW)
Data is written into the memory if $\overline{WE}$ is LOW and read from the memory if $\overline{WE}$ is HIGH.

$\overline{OE}$ Output Enable (Input, Active LOW)
Read cycles can be executed only when $\overline{OE}$ is LOW.

ABSOLUTE MAXIMUM RATINGS (Note 11)

Storage Temperature ..... −65 to +150°C
Ambient Temperature with
Power Applied ..... −55 to +125°C
Supply Voltage ..... −0.5 V to +7.0 V
Signal Voltage with
Respect to Ground ..... −3.0 V to +7.0 V
Power Dissipation ..... 1.0 W
DC Output Current ..... 10 mA

*Maximum ratings are to be for system design reference, parameters given may not be 100% tested by AMD.

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES (Note 3)

Commercial (C) Devices
Ambient Temperature (T_A) ..... 0 to +70°C
Supply Voltage (V_{CC}) ..... +4.5 V to +5.5 V

Military* (M) and Extended Commercial (E) Devices
Case Temperature (T_A) ..... −55 to +125°C
Supply Voltage (V_{CC}) ..... +4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted) (Note 3)

Parameter Symbol	Parameter Description	Test Conditions		Am9128-90 Am9128-10		Am9128-15		Am9128-70 Am9128-12 Am9128-20		Unit
				Min.	Max.	Min.	Max.	Min.	Max.	
I_{OH}	Output HIGH Current	V_{OH} = 2.4 V	V_{CC} = 4.5 V	−2		−2		−2		mA
I_{OL}	Output LOW Current	V_{OL} = 0.4 V		4		4		4		mA
V_{IH}	Input HIGH Voltage			2.0	V_{CC} + 1.0	2.0	V_{CC} + 1.0	2.0	V_{CC} + 1.0	V
V_{IL}	Input LOW Voltage			−0.5	0.8	−0.5	0.8	−0.5	0.8	V
I_{IX}	Input Load Current	$V_{SS} \leq V_I \leq V_{CC}$			10		10		10	μA
I_{OZ}	Output Leakage Current	$V_{SS} \leq V_O \leq V_{CC}$ Output Disabled			10		10		10	μA
C_{IN}	Input Capacitance (Note 12)	Test Frequency = 1.0 MHz, T_A = 25°C, All pins at 0	V_{CC} = 5.0 V		6		6		6	pF
$C_{I/O}$	Input/Output Capacitance (Note 12)				7		7		7	
I_{CC}	V_{CC} Operating Supply Current	Max. V_{CC}, $\overline{CE} \leq V_{IL}$ Outputs Open	COM'L		120		100	140		mA
			MIL/E-COM'L		180		150	150		
I_{SB}	Automatic $\overline{CE}$ Power Down Current	Max. V_{CC}, $\overline{CE} \geq V_{IH}$	COM'L		15		15	30		mA
			MIL/E-COM'L		30		30	30		
I_{PO}	Peak Power On Current (Note 12)	V_{CC} = GND to V_{CC} Max. $\overline{CE} \geq V_{IH}$ (Note 2)	COM'L		15		15	30		mA
			MIL/E-COM'L		30		30	30		

Notes:
1. The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input setup and hold timing should be referenced to the rising edge of the signal that terminates the write.
2. A pull up resistor to V_{CC} on the $\overline{CE}$ input is required during power up to keep the device deselected, otherwise I_{PO} will exceed values given.
3. For test and correlation purposes, ambient temperature is defined as the "Instant-on" case temperature.
4. At any given temperature and voltage condition, t_{HZ} is less than t_{LZ}.
5. $\overline{WE}$ is HIGH for read cycle.
6. Device is continuously selected, $\overline{CE} = V_{IL}$.
7. Address valid prior to or coincident with $\overline{CE}$ transition LOW.
8. $\overline{OE} = V_{IL}$.
9. C_L = 30 pF.
10. Transition is measured from 1.5 V on the input to V_{OH} − 500 mV and V_{OL} + 500 mV on the outputs using the load shown in Switching Test Circuits. C_L = 5 pF.
11. The products described by this specification include internal circuitry designed to protect input devices from damaging accumulations of static charge. It is suggested, nevertheless, that conventional precautions be observed during storage, handling, and use to avoid exposure to excessive voltages.
12. The parameter is guaranteed by characterization, but is not tested.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted.)

Am9128-70, -90, -10

No.	Parameter Symbol	Parameter Description		Am9128-70 Min.	Am9128-70 Max.	Am9128-90 Min.	Am9128-90 Max.	Am9128-10 Min.	Am9128-10 Max.	Unit
READ CYCLE										
1	t_{RC}	Read Cycle Time		70		90		100		ns
2	t_{ACC}	Address Access Time (Note 9)			70		90		100	ns
3	t_{ACS}	Chip Select Access Time (Note 9)			70		90		100	ns
4	t_{OE}	Output Enable Time (Note 9)	COM'L		40		N/A		50	ns
			MIL		N/A		50		N/A	
5	t_{OH}	Output Hold Time from Address Change		5		5		5		ns
6	t_{CLZ}	Output in Low-Z from $\overline{CE}$ (Notes 4, 10, 12)		5		5		5		ns
7	t_{CHZ}	Output in Hi-Z from $\overline{CE}$ (Notes 4, 10, 12)			35		40		40	ns
8	t_{OLZ}	Output in Low-Z from $\overline{OE}$ (Notes 4, 10, 12)		5		5		5		ns
9	t_{OHZ}	Output in Hi-Z from $\overline{OE}$ (Notes 4, 10, 12)			30		35		35	ns
10	t_{PU}	Chip Selection to Power-Up Time (Note 12)		0		0		0		ns
11	t_{PD}	Chip Deselection to Power-Down Time (Note 12)			40		45		50	ns
WRITE CYCLE										
12	t_{WC}	Write Cycle Time		70		90		100		ns
13	t_{CW}	Chip Selection to End of Write (Note 1)	0 to +70°C	60		N/A		90		ns
			−55 to −125°C	N/A		80		N/A		
14	t_{AS}	Address Setup Time		5		10		10		ns
15	t_{WP}	Write Pulse Width (Note 1)		40		55		60		ns
16	t_{WR}	Write Recovery Time		5		5		5		ns
17	t_{DS}	Data Setup Time		30		35		40		ns
18	t_{DH}	Data Hold Time		5		5		5		ns
19	t_{WLZ}	Output in Low-Z from $\overline{WE}$ (Notes 4, 10, 12)		5		5		5		ns
20	t_{WHZ}	Output in Hi-Z from $\overline{WE}$ (Notes 4, 10, 12)			30		35		35	ns
21	t_{AW}	Address to End of Write		65		80		80		ns

Notes: See notes following DC Characteristics table.

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SWITCHING CHARACTERISTICS (Cont'd.)

Am9128-12, -15, -20

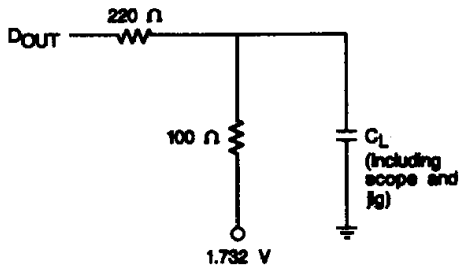
No.	Parameter Symbol	Parameter Description		Am9128-12 Min.	Am9128-12 Max.	Am9128-15 Min.	Am9128-15 Max.	Am9128-20 Min.	Am9128-20 Max.	Unit
READ CYCLE										
1	t_{RC}	Read Cycle Time		120		150		200		ns
2	t_{ACC}	Address Access Time (Note 9)			120		150		200	ns
3	t_{ACS}	Chip Select Access Time (Note 9)			120		150		200	ns
4	t_{OE}	Output Enable Time (Note 9)	COM'L		N/A		60		70	ns
			MIL		70		70		80	
5	t_{OH}	Output Hold Time from Address Change		5		5		5		ns
6	t_{CLZ}	Output in Low-Z from $\overline{CE}$ (Notes 4, 10, 12)		5		5		5		ns
7	t_{CHZ}	Output in Hi-Z from $\overline{CE}$ (Notes 4, 10, 12)			50		55		55	ns
8	t_{OLZ}	Output in Low-Z from $\overline{OE}$ (Notes 4, 10, 12)		5		5		5		ns
9	t_{OHZ}	Output in Hi-Z from $\overline{OE}$ (Notes 4, 10, 12)			45		50		50	ns
10	t_{PU}	Chip Selection to Power-Up Time (Note 12)		0		0		0		ns
11	t_{PD}	Chip Deselection to Power-Down Time (Note 12)			55		60		60	ns
WRITE CYCLE										
12	t_{WC}	Write Cycle Time		120		150		200		ns
13	t_{CW}	Chip Selection to End of Write (Note 1)	COM'L	N/A		120		150		ns
			MIL	105		130		160		
14	t_{AS}	Address Setup Time		10		20		20		ns
15	t_{WP}	Write Pulse Width (Note 1)		70		85		100		ns
16	t_{WR}	Write Recovery Time		5		5		5		ns
17	t_{DS}	Data Setup Time		45		50		60		ns
18	t_{DH}	Data Hold Time		5		5		5		ns
19	t_{WLZ}	Output in Low-Z from $\overline{WE}$ (Notes 4, 10, 12)		5		5		5		ns
20	t_{WHZ}	Output in Hi-Z from $\overline{WE}$ (Notes 4, 10, 12)			50		50		50	ns
21	t_{AW}	Address to End of Write		105		120		120		ns

Notes: See notes following DC Characteristics table.

SWITCHING TEST CONDITIONS

Input Pulse Levels	.4 to 2.4 V
Input Rise and Fall Times	10 ns
Input Timing Reference Levels	1.4 V
Output Timing Reference Levels	1.4 V

SWITCHING TEST CIRCUIT



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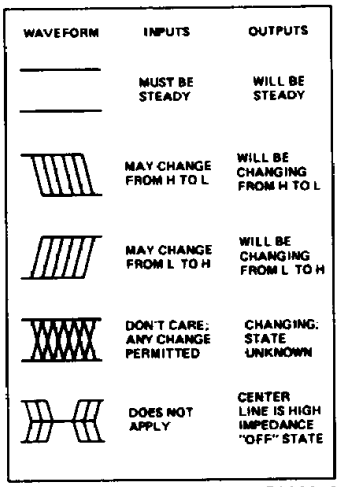
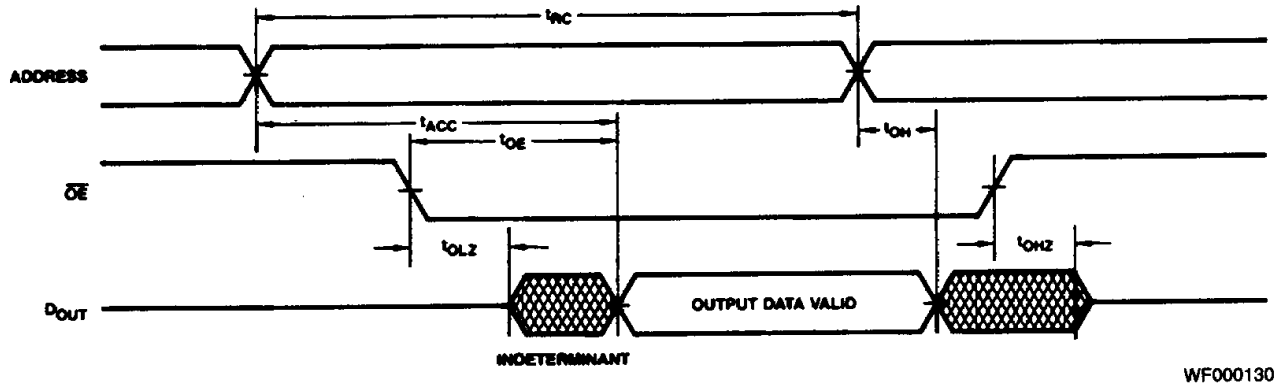
SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORMS

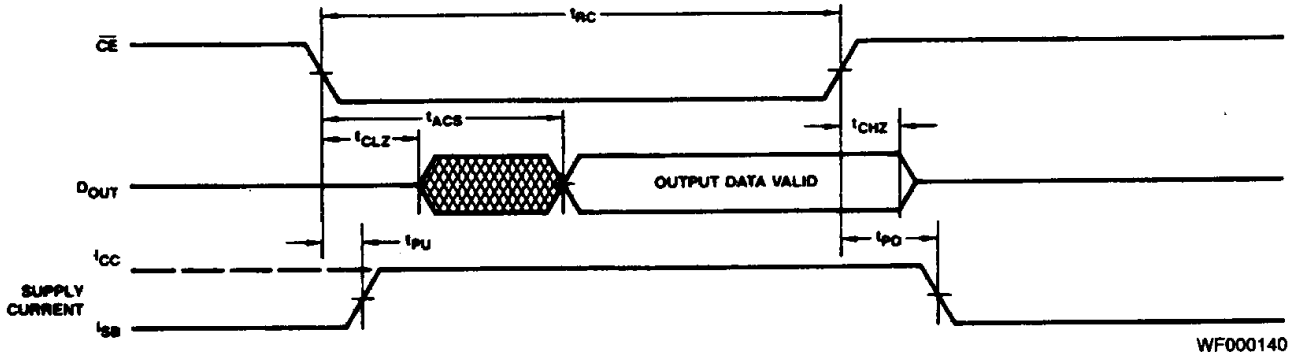


KS000010



WF000130

Read Cycle No. 1 (Notes 5, 6)

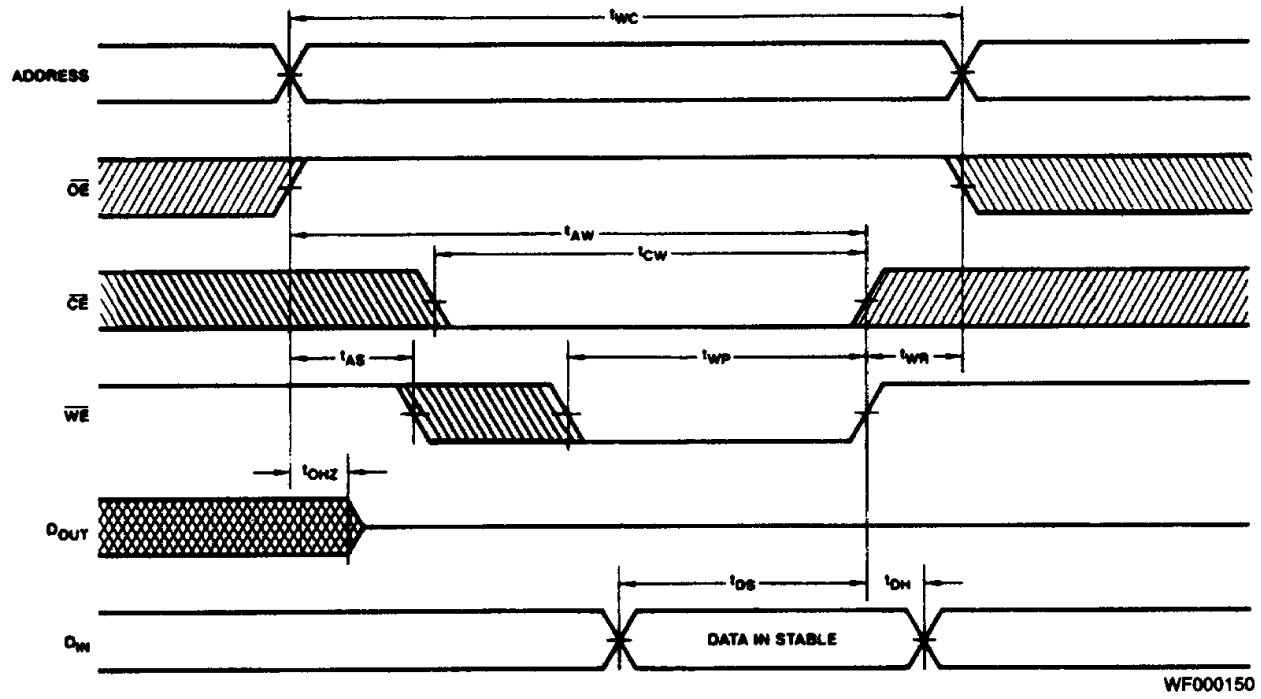


WF000140

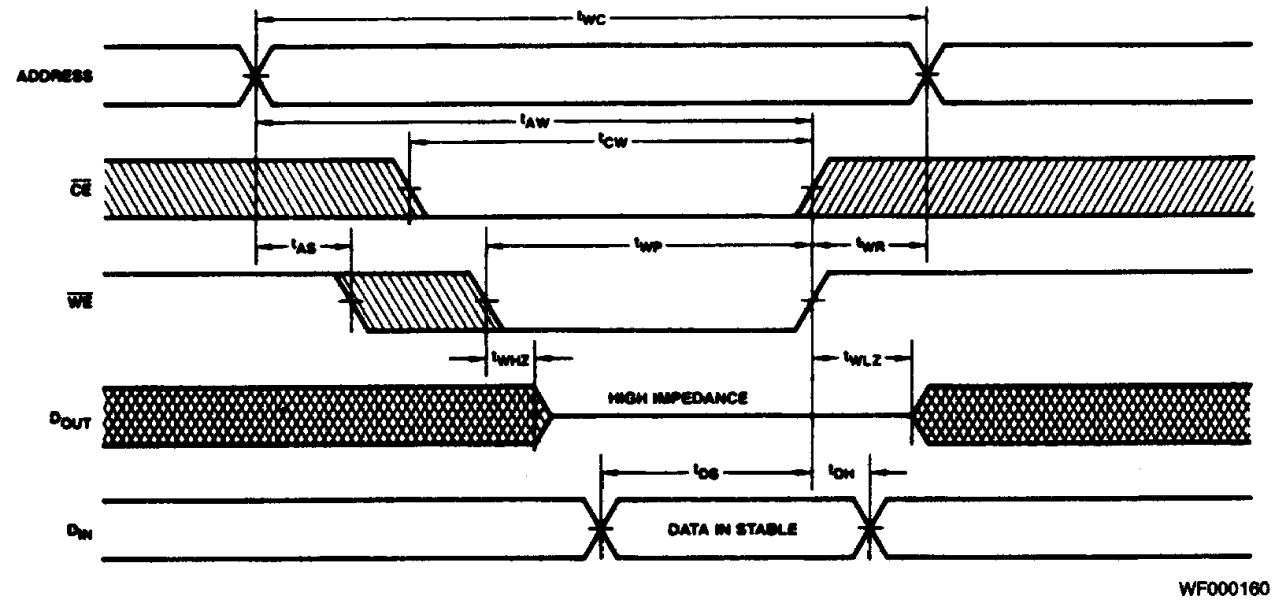
Read Cycle No. 2 (Notes 5, 7, 8)

Notes: See notes following DC Characteristics table.

SWITCHING WAVEFORMS (Cont'd.)



Write Cycle No. 1

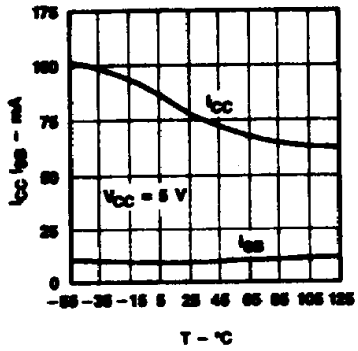


Write Cycle No. 2 (Notes 7, 8)

Notes: See notes following DC Characteristics table.

TYPICAL PERFORMANCE CURVES

Supply Current Versus Ambient Temperature



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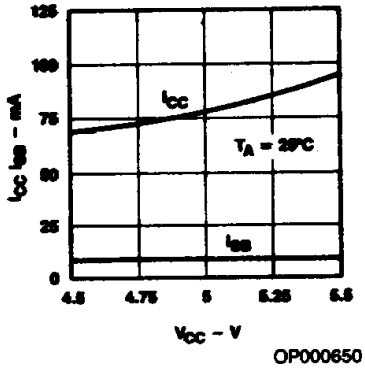
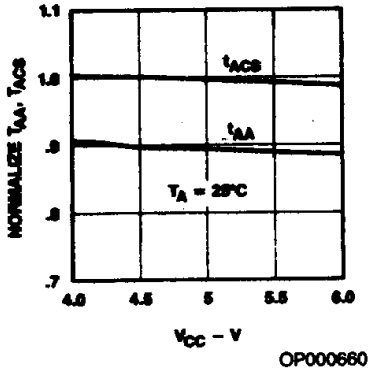
Supply Current Versus Supply Voltage



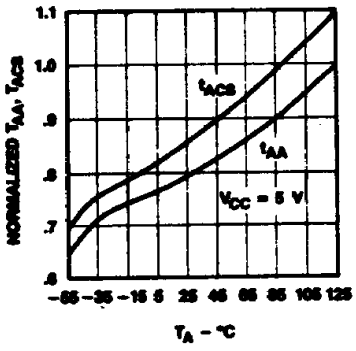
OP000650

Normalized Access Time Versus Supply Voltage



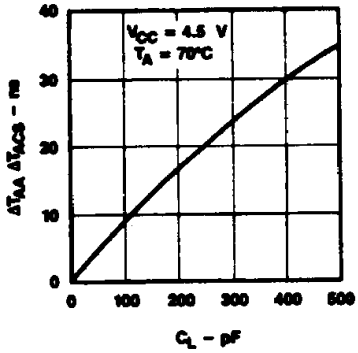
OP000660

Normalized Access Time Versus Ambient Temperature



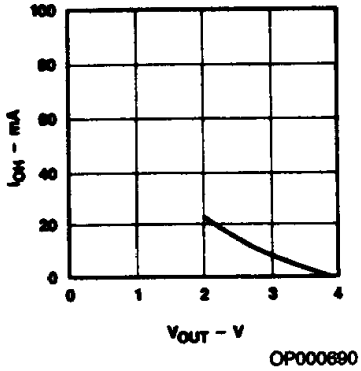
OP000670

Access Time Change Versus Output Loading



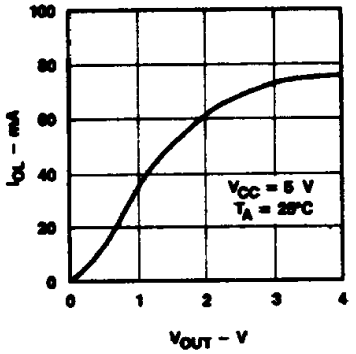
OP000680

Output Source Current Versus Output Voltage



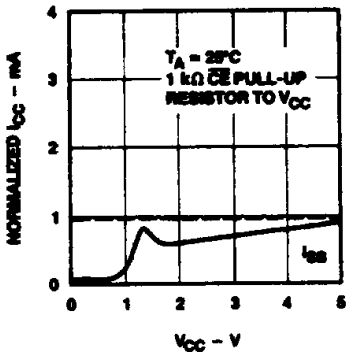
OP000690

Output Sink Current Versus Output Voltage



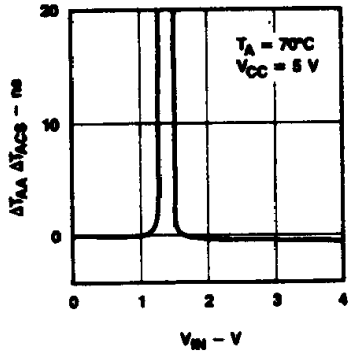
OP000700

Typical Power-On Current Versus Power Supply



OP000710

Access Time Change Versus Input Voltage



OP000720

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